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Ar:N_2 - a non-universal glass

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The bias energies of various two-level systems (TLSs) and their strengths of interactions with the strain are calculated for Ar:N_2 glass. Unlike the case in KBr:CN, a distinct class of TLSs having weak interaction with the strain and untypically small bias energies is not found. The addition of CO molecules introduces CO flips which form such a class of weakly interacting TLSs, albeit at much lower coupling than are typically observed in solids. We conclude that because of the absence of a distinct class of weakly interacting TLSs, Ar:N_2 is a non-universal glass, the first such system in three dimensions and in ambient pressure. Our results further suggest that Ar:N_2:CO may show universal properties, but at temperatures lower than ≈ 0.1 K, much smaller than typical temperature ≈ 3 K associated with universality, because of the untypical softness of this system. Our results thus shed light on two long standing questions regarding low temperature properties of glasses: the necessary and sufficient conditions for quantitative universality of phonon attenuation, and what dictates the energy scale of ≈ 3 K below which universality it typically observed.

I. INTRODUCTION

One of the remarkable phenomena in condensed matter physics is the universality of properties related to phonon attenuation at temperatures smaller than ≈ 3 K in a large class of materials, ranging from amorphous solids, to disordered lattices, disordered polymers, and quasicrystals[1–3]. The fact that universality is also quantitative, both in the magnitude of phonon attenuation, and in the energy scale dictating the temperature below which the phenomenon is observed, and the broadness of systems exhibiting it, attests to the presence of a mechanism, pertaining to the disordered state itself, that dictates phonon attenuation in disordered systems. Exceptions to universality are rare, and have been observed only in two-dimensional films under special conditions; hydrogenated silicon films[4] and silicon nitride films under applied stress[5].

Theoretically, much of the characteristics of disordered solids can be understood within the "standard tunneling model" (STM)[6–8], which introduces tunneling two-level systems (TLSs); their interaction with the phonon field dominating phonon attenuation. Within the STM all phonon attenuation properties are given in terms of the "tunneling strength" $C_0 \approx 0.1 n\gamma^2/(\rho v^2)$, where n is the density of states (DOS) of the TLSs, γ is their interaction constant with the phonon field (strain), ρ is the mass density, and v the acoustic velocity. However, the STM can not explain what is the nature of the TLSs, why is phonon attenuation universal among different systems, and the origin of the energy scale of ≈ 3 K dictating the universality regime.

Attempts to understand the nature of the TLSs include "top-down" approaches, trying to construct a theory which relies only on the glassy state of matter[9–14], and "bottom-up" approaches, attempting to identify the relevant TLSs in a given system, and then generalize to all disordered systems showing universality[15–18]. Specifically, the KBr:CN system was scrutinized, and it was suggested early on[15, 18] that it is the flipping of the CN^- impurities (and not e.g. their rotations) that make for the relevant TLSs dictating the universal properties in this system. To test this idea an experiment was carried on the Ar:N_2 glass, which does not possess single impurities that can flip, with and without the addition of CO impurities[19]. The fact that the linear term in the specific heat, corresponding to the DOS of the TLSs, had little if any dependence on the CO concentration, was interpreted as a refutation of the molecular flips as being the relevant TLSs dictating universality. Little attention was paid to the fact that Ar:N_2 did not exhibit universal phonon attenuation as observed in its thermal conductivity[20].

Recently, the fact that CN^- flips in KBr:CN indeed constitute the TLSs dictating universal phonon attenuation and the linear specific heat in KBr:CN at $T \lesssim 3$ K received overwhelming support. Using Density Functional Theory and ab-initio calculations it was shown that the coupling of CN^- flips to the strain $\gamma_{\rm f}^{\rm CN^-} \approx 0.1$ eV, whereas the coupling of CN^- rotations to the strain $\gamma_{\rm r}^{\rm CN^-} \approx 3$ eV[21], the former value agreeing with the experimental value obtained for the relevant TLSs at low temperatures[16, 22]. Furthermore, the DOS of CN^- flips and CN^- rotations was calculated numerically from first principles[23], where it was shown that CN^- flips are abundant at energies $\lesssim 3$ K, whereas CN^- rotations are scarce below ≈ 10 K, as they are gapped by the weakly interacting flips. All these findings are in excellent agreement with the recently introduced two-TLS model[24, 25], which derives the universality of phonon attenuation and the energy scale of ≈ 3 K for the universal regime as a consequence of the existence of two classes of TLSs differentiated by their interaction with the strain, based on the symmetry of the TLSs under inversion. Yet, the above mentioned results in KBr:CN and the two-TLS model seems to be at odds with the

experimental results in Ar:N_2:CO, as the latter suggest that the CO flips have no significant contribution to the low energy properties of Ar:N_2:CO.

In this paper we reconcile this alleged discrepancy. Using a discrete atomic model employing the Lennard Jones (LJ) potential, as well as density function theory (DFT), we calculate the TLS-strain interaction constant for various TLSs in both Ar:N_2 and Ar:N_2:CO systems. For the latter we find that indeed CO flips have a much weaker interaction with the phonon field compared to all other excitations studied, in agreement with the two-TLS model, and similar to CN^- flips in KBr:CN. However, because of the untypical softness of the Ar:N_2:CO lattice, and the resulting smallness of TLS-phonon interactions (both $\gamma_{\rm f}^{\rm CO}$ and $\gamma_{\rm r}^{\rm CO}$ are smaller than $\gamma_{\rm f}^{\rm CN^-}$ and $\gamma_{\rm r}^{\rm CN^-}$, by a factor of ≈ 3 and by an order of magnitude, respectively), we expect universality in Ar:N_2:CO to appear only below $T \approx 0.1$ K. For Ar:N_2, where single impurity flips are absent, we find a related absence of a distinct class of TLSs weakly interacting with the strain. We then study the DOS of TLS bias energies for the different TLS configurations, and find again no distinct class of TLSs typified by low bias energies. Since Ar:N_2 does not fulfill the necessary conditions for universality as are suggested by the two-TLS model[24], and in view of its low temperature thermal conductivity as was obtained experimentally, we argue that Ar:N_2 constitutes a first example of a non-universal strongly disordered glass in three dimensions and in ambient pressure.

II. METHODS

For most of our calculations, we have employed a model developed expressly for this purpose. It is based on the iterative solution, using previously described numerical methods[26, 27], of a mesh of non-linear springs with Lennard-Jones $r^6 - r^{12}$ potential[28] to describe all the interactions. In particular, we assumed the following Lennard-Jones parameters $\epsilon_{Ar-Ar} = 3.7936 \cdot 10^{-4}\mathrm{E_h}$, $\sigma_{Ar-Ar} = 6.3302 r_B$,[29] $\epsilon_{Ar-N} = 2.1263 \cdot 10^{-4}\mathrm{E_h}$, $\sigma_{Ar-N} = 6.3306 r_B$,[30] $\epsilon_{N-N} = 0.3601\mathrm{E_h}$, $\sigma_{N-N} = 2.0749 r_B$, [31], $\epsilon_{N_2-N_2} = 1.3916 \cdot 10^{-4}\mathrm{E_h}$, $\sigma_{N_2-N_2} = 6.3136 r_B$,[32], taking measures to deal with the numerical instabilities that arise from the double N-N potential (intramolecular and intermolecular).

Starting from a pristine Ar lattice (a pure Ar network with crystallographic positions[30]), we very gradually raise the concentration of N_2, adding them one by one. We do this up to a limit of 20%Ar:80%N_2. As the Ar:N_2 ratio is decreased and to minimize artificial structural stress, we adjust the lattice intersite distance to match the real density of Ar:N_2 mixtures.

In the N_2 enrichment process of the Ar lattice the goal is to minimize the energy and at the same time to obtain a variety of structures so that the end result is statistically representative. To achieve this, each new N_2 impurity added takes a random position and orientation, but every time that we are about to add a new impurity, we choose up to 50 random positions and orientations for it, starting from the same equilibrium lattice. For each of these 50 possibilities, the structure of the lattice is relaxed, allowing the positions of all atoms and the orientations of all molecules to adjust slightly. Note that in the very first step, when the previous position was the pristine Ar lattice, this generates 50 second-step structures, branching out the procedure. Subsequent steps do not continue with the branching and instead optimize the energy: for each one of the 50 structures with n impurities we obtain 50 with $n+1$, but keep only the most stable one.

We end up with 50 different low-energy configurations for each Ar:N_2 ratio. For each of these, a Monte-Carlo procedure is used allowing for random orientation tunneling of each N_2 molecule (25 sweeps) for further lowering the energy. After each Monte-Carlo step the structure is relaxed. At the end of the Monte-Carlo procedure, the system is ready to suffer the different kinds of excitations as described below.

The efficiency of this model allows the use of rather large fragments, a continuous exploration of the range of Ar:N_2 ratios and the obtention of statistically significant number of low-energy configurations and all their relevant excitations. We performed calculations both for 2D and 3D (hcp and fcc) structures, but focused mainly on 2D, where reaching good low energy states is easier because of the smaller number of stable N_2 orientations (6 in 2D vs. 12 in 3D), and at the same time the constraints for finding centrosymmetric TLSs are less stringent than in 3D, see below. More details about the model can be found in a dedicated article. [33]

To avoid border effects, we only study excitations within the seven central positions of a 9x9 lattice (Fig. 1 (a)). Within these seven positions, we consider all possible N_2-N_2 (or Ar-N_2) pairs and the three types of excitations depicted in Fig. 1 (b), (c), (d) and detailed in the next section.

For the purposes of evaluating the density of states, we define the excitation energy $\mathrm{E_{bias}}$ (1) as the difference between the calculated potential energies of the excited state V_e and its corresponding ground state V_g:

$$\mathrm{E_{bias}} = (V_e - V_g)\,. \tag{1}$$

To evaluate TLS-phonon coupling $\gamma(2)$ we apply a 0.5% mesh contraction to obtain the difference between potential energies

$$\gamma = \left(V_g^{ph} - V_g\right) - \left(V_e^{ph} - V_e\right)\,. \tag{2}$$

Here superscript ph indicates the system after the phonon and subscripts g and e indicate ground and excited state, respectively. We have employed two different protocols, where in the first the system is relaxed after the mesh contraction and in the second it is not relaxed. Whereas single γ values differ between these two protocols, differences between the two protocols in the statistical distri-

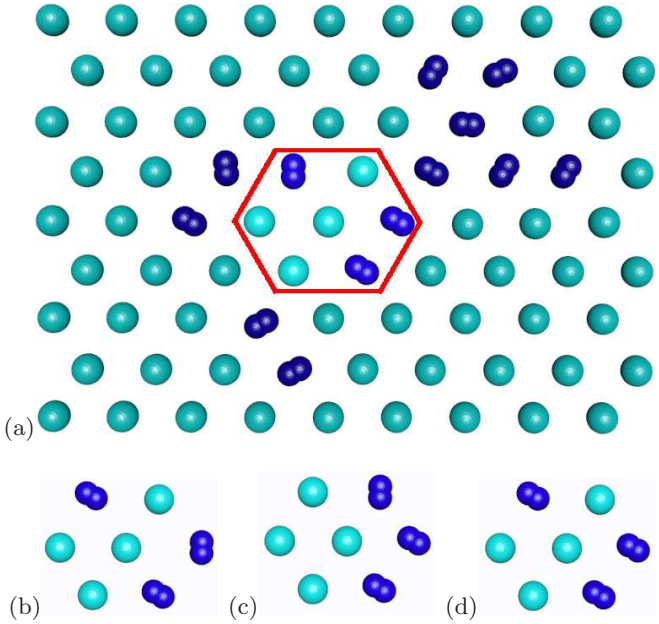

FIG. 1: (a) Initial configuration, highlighting the central hexagon where excitations take place. (b)-(d) Different excited states starting from the same initial state configuration. (b) flip-flop (c) Ar-tunneling (d) rotation.

bution of γ values as is plotted in Fig. 2 was found to be negligible.

For a few calculations on small 2D fragments, we employed the same DFT methods as presented in [21] to extract the values of the TLS-phonon interaction energy γ of the different TLSs as explained above. We also use this methodology to extract the values of the TLS-phonon interaction and estimate γ for CO head-tail flips (exactly analogous to the CN^- flips in [21]).

III. RESULTS

As an initial exploration, we start from pristine Ar networks, either 2D or 3D, and substitute N_2 for Ar at certain positions and in certain orientations. Then we minimize the energy allowing only small displacements, and for each starting configuration we arrive at a unique (local) ground state, in the sense that we found no off-center displacement in any single N_2 molecule or in any single Ar atom that could give rise to a centrosymmetric TLS.

On the other hand we did find pairs of low-energy configurations that relate to each other through an inversion center, which we denote τ-TLSs. Those involve, in the simplest case, the exchange of orientation of two non-parallel neighbouring N_2, which we label as *flip-flop*. Note that this is actually a fragile, environmental-dependent phenomenon, where the low-energy part of a complex spectrum of two or more non-centrosymmetric (denoted S-type) TLSs happens to take the form of a $\tau - TLS$. This is a fundamental difference with the CN^- case, where each molecule had an intrinsic, built-in, τ-TLS in the form of a CN^- flip. Because of this, the variable influence of an extra neighbouring N_2 results in a wide spectrum for the interaction strength of flip-flop excitations with the strain, ranging from γ_f to γ_r.

A different, similarly fragile, τ-TLS can be defined if we consider a tunneling process where an Ar atom and an N_2 molecule exchange positions. This we label as *Ar-tunnel*. Finally, any change in orientation of a single given N_2 molecule always constitutes an S-TLS. Except where otherwise stated, in our calculations we choose an orientation change such that an N_2 adopts the orientation of a neighbouring, non-parallel N_2, and label this as *rotation*. An example of each of these three collective TLSs is shown in Figure 1.

To evaluate the character of these collective TLSs in realistic situations, we proceed with a systematic exploration at increasing concentrations of N_2 as detailed in section II and in reference [33]. As can be seen in Fig. 2, we find for all TLSs distributions of bias energies with typical values of $\gamma \approx 0.3 - 0.5$eV and $E_{\text{bias}} \approx 10meV$, rather than markedly distinct behaviors for different TLS types as would be expected for the τ-S-TLSs model and was observed for KBr:CN [21]. Of course, for every kind of TLS there are particular TLSs which are almost uncoupled to phonons coming from a particular direction. Note that in our model the phonon compression is not randomized, but is instead applied in one of the special directions of the lattice. Therefore, it is expected that there is a sub-class within each type of TLSs that presents low values of γ to phonons coming from a special direction. The difference with the KBr:CN case is the absence of two full (symmetry-defined) classes of TLSs τ, S where the phonon coupling γ is, for any direction, much lower in τ TLSs compared with S TLSs. The absence of such a class of TLSs is caused by the dramatic perturbation of the centrosymmetric TLSs by the nearest neighbours in the Ar:N_2 system. While the interaction energies are the same in 2D and 3D, there are 12 nearest-neighbours in 3D compared with just 6 in 2D, meaning that the centrosymmetric nature of collective TLSs will be, if at all, even more fragile in 3D. We thus expect a similar wide distribution of the coupling constants also for Ar:N_2 in three dimensions.

Notably, we also find that the obtained values for the TLS-strain interaction strengths are small compared with the γ_r determined for KBr:CN in a previous work.[21]. We have to emphasize that, up to a point, this was to be expected. Indeed, N_2 and Ar (and CO, for that matter) are very different from the vast majority of substances, in that they are formed by molecules that are very weakly bounded to each other, compared with almost anything else. The main interactions among these molecules are van der Waals rather than electrostatic. Besides causing their extremely low boiling- and melting temperatures, this also results in the low energy of their crystal defects. As an example, the energy of a vacancy-type crystal de-

fect in Ar is < 0.1eV, while for iron –which is malleable– this energy is > 1eV.

Nevertheless, to further test this smallness of the γ, we construct smaller lattices which we treat with the DFT methodology that was originally used for the KBr:CN system [21]. We employ the B3LYP functional and the 6-311G basis set, plus a better basis set 6-311+G* to verify the results. We confirm that the obtained γ_r are an order of magnitude smaller than those obtained by the same methodology in KBr:CN (see table I).

TABLE I: γ_r(rotation) in different configurations. Problem A: 3x3 pristine Ar lattice with a central N_2; A2 is the same lattice but using a 6-311+G* basis set. Problem B: 5x5 pristine Ar lattice with a central N_2. problem C: 5x5 pristine Ar lattice with three nearest neighbours N_2 in the central line, oriented parallel to each other and perpendicular to the line defined by their centers.

	A	A2	B	C
γ_r (DFT,eV)	0.60	0.56	0.320	0.22

We then used the same methodology to estimate γ for CO flips in Ar:N_2:CO samples. we have found that γ_f is an order of magnitude smaller than γ_r, and that like in the case of γ_r, the values of γ_f are at least a factor of three below the values found for flip excitations in KBr:CN (Table II). The tests were done on pristine 5x5 Ar fragments where some of the Ar atoms in the central hexagon were substituted by N_2 molecules at random orientations. In each configuration, we applied either horizontal or vertical phonons. For convenience and brevity, we label the N_2 impurities according to their clock position and orientations.

TABLE II: γ_f for a CO impurity in the center of different 5x5 fragments. The low-state impurity is defined by its clock-orientation (e.g. 3=horizontal). All N_2 impurities are in the first hexagon and thus are uniquely defined by their clock-position and -orientation, in that order.

(CO)(N_2)(N_2)(N_2)	$\gamma_{f,h}$ (meV)	$\gamma_{f,v}$ (meV)
(3)(1,3);(5,3);(9,6)	31.8	34.6
(3)(1,3);(3,4);(5,1)	33.7	47.6
(5)(1,3);(3,3);(9,6)		6.3

IV. DISCUSSION AND CONCLUSIONS

KBr:CN is one of many disordered lattices showing low temperature phonon attenuation properties which are equivalent in both functional form and magnitude to those observed in all amorphous solids, and are thus dubbed universal. For KBr:CN it was shown that universality is intimately related to the existence of bi-modality in the typical values of the TLS-strain coupling; inversion symmetric (flips, "τ") TLSs having a typically weak interaction with the strain and inversion asymmetric (rotations, "S") TLSs having a typically strong interaction with the strain. The ratio between the two interaction constants, $g \equiv \gamma_f/\gamma_r$, dictates the ratio between the typical bias energies of τ-TLSs and S-TLSs, and consequently the universality and smallness of the tunneling strength. The energy scale related to the temperature below which universality is observed is given by the typical bias energy of the τ-TLSs: $\gamma_f\gamma_r/(\rho v^2 R_0^3)$, where R_0 is the typical distance between impurities. This energy, being g times smaller than the glass temperature, is typically a few Kelvin.

As we found for the KBr:CN system[21], we find here also for the Ar:N_2:CO system a bi-modality in the values of the interaction constants of TLSs with the strain, where CO flips constitute a distinct group of weakly interacting TLSs, *i.e.* γ_f has a typical value much smaller than all other calculated TLS-phonon coupling constants, including that of CO rotation. Thus, we expect the DOS of TLSs in Ar:N_2:CO to show a similar structure to that found in KBr:CN[23], where the τ-TLSs dominate the spectrum at low energies, have a roughly constant DOS, and thus dominate phonon attenuation. Furthermore, this structure of DOS coupled with the above mentioned bi-modality in the typical strengths of the TLSs interaction with the strain necessarily leads to qualitative and quantitative universality in phonon attenuation. We thus expect Ar:N_2:CO to show all the universal properties known in glasses. However, since both γ_f and γ_r are untypically small for CO excitations in Ar:N_2:CO, we expect universality in this system to be present only at temperatures smaller than ≈ 0.1 K.

The situation in Ar:N_2, in the absence of CO impurities, is very different, since no single impurity flips exist. Furthermore, we have shown here that no other excitation can play the role of such flips in having a small typical interaction with the strain and small typical bias energies in comparison to all other excitations in this system; we find no off-center displacements of Ar atoms or N_2 molecules; we then show explicitly that N_2 rotations and pair excitations have strain interactions of typical value $\approx \gamma_r$ and typical bias energies $\approx 10meV$. This is true also for pair excitations possessing local inversion symmetry, because the proximity of each of the pair molecules (or Ar atom) to other N_2 molecules in the solid yields large typical values for TLS-strain interactions and TLS bias energies. Although we have not checked all types of excitations, including those involving larger number of impurities, we can not foresee a scenario in which any such type of excitation would give rise to a systematically weak interaction with the strain. Indeed, although excess low temperature specific heat is found in Ar:N_2, resulting from an abundance of low energy excitations, its thermal conductivity was found to have a very different temperature dependence than that typical for glasses at low temperatures[20]. We therefore argue that Ar:N_2 is a non-universal glass, the first among strongly disordered systems having tunneling states, whereas the apparent similarity between the values of the specific heat in Ar:N_2 and Ar:N_2:CO[19] is limited to the relatively

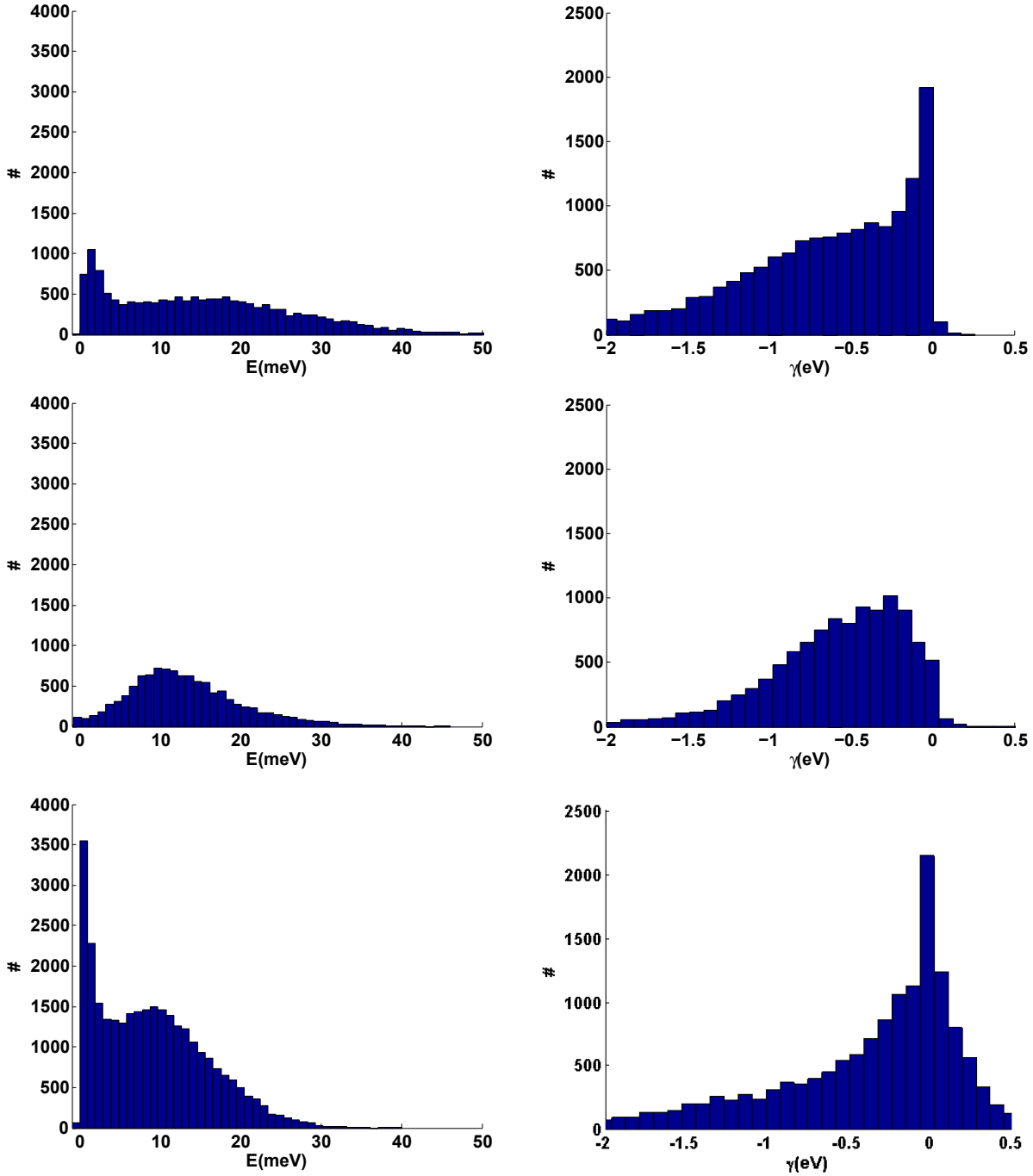

FIG. 2: Numerical results of 50 independent histories with Ar:N_2 ratios ranging from 0.8:0.2 to 0.2:0.8. Left: Density of states of bias energies [Eq. (1)]. Right: frequency of encountered values for γ [Eq. (2)]. Exitation types from top to bottom: flipflop; Ar-tunnel; rotation [see Fig. 1].

high temperature, in comparison to the energy scale of the bias energies of CO flips, studied experimentally.

Our results here are tightly connected to the discussion regarding the necessary and sufficient conditions to observe universality in disordered lattices. In addition to strong strain disorder and tunneling TLSs[34, 35], the existence of a distinct class of TLSs weakly interacting with the strain is required. This is in line with the two-TLS model, showing that such a class of low energy excitations is an outcome of the existence of inversion symmetric TLSs. Indeed, we find that Ar:N_2, which does not show universal properties at low temperatures, does not possess local inversion symmetric flip excitations, and does not have a distinct class of weakly interacting TLSs. At the same time, we refute the notion that CO flips in Ar:N_2:CO do not contribute to the low energy properties

of this system. In that we refute the central criticism to the sufficiency of the above conditions, including the presence of inversion symmetric (flip) excitations, for the appearance of universality at low temperatures. Furthermore, our results suggest that the rather universal temperature of ≈ 3 K below which universality is observed is related also to the fact that typical interactions between near neighbor impurities are rather similar in different solids, Ar:N_2:CO being a marked exception.

Our conclusions here are based on the two-TLS model, and its proven applicability to disordered lattices showing universality. Were these conclusion to apply also to amorphous solids, it would suggest the generic existence in amorphous solids of local excitations with markedly weak interaction with the phonon field and small bias energies. It would therefore be of much interest to check the applicability of the two-TLS model to amorphous solids.

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